

Description

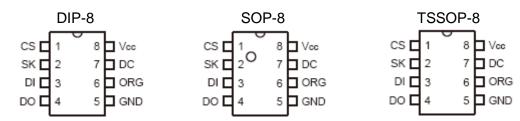
The ACE93C46/56/66 provides 1024/2048/4096 bits of serial electrically erasable programmable read only memory (EEPROM) organized as 64/128/256 words of 16 bits each, when the ORG pin is connected to VCC and 128/256/512 words of 8 bits each when it is tied to ground. The ACE93C46/56/66 is available in space-saving 8-lead PDIP, 8-lead TSSOP and 8-lead JEDEC SOIC packages. The ACE93C46/56/66 is enabled through the Chip Select pin (CS), and accessed via a 3-wire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SK). Upon receiving a Read instruction at DI, the address is decoded and the data is clocked out serially on the data output pin DO. The WRITE cycle is completely self-timed and no separate erase cycle is required before write. The Write cycle is only enabled when it is in the Erase/Write Enable state. When CS is brought "high" following the initiation of a write cycle, the DO pin outputs the Ready/Busy status.

Features

- Low-voltage operation 1.8 (VCC=1.8V to 5.5V)
- Three-wire serial Interface
- 2MHz clock rate(5V) compatibility
- Self-timed write cycle (5 ms max)
- High-reliability Endurance: 1 Million write cycles

Data retention: 100 Years

Packaging Type



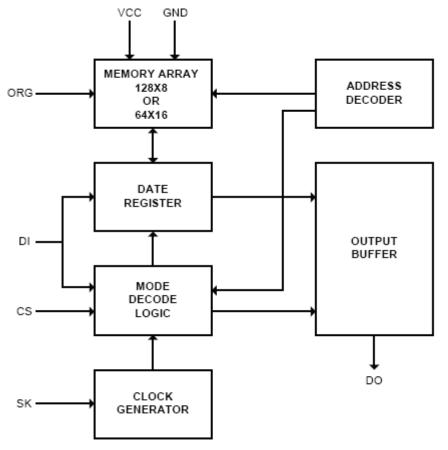
Pin Configurations

Pin Name	Function
CS	Chip select
SK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
GND	Ground
Vcc	Power Supply
ORG	Internal Organization
DC	Don't Connect



Block Diagram

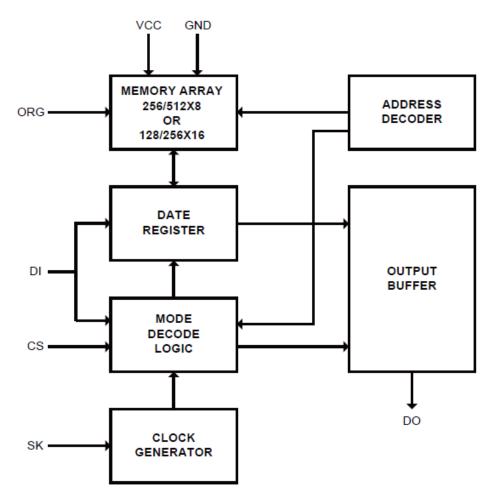
ACE93C46



Note: When the ORG pin is connected to VCC, the "x 16" organization is selected. When it is connected to ground, the "x 8" organization is selected. If the ORG pin is left unconnected and the application does not load the input beyond the capability of the internal 1 Meg ohm pullup, then the "x 16" organization is selected.



ACE93C56/66



Note: When the ORG pin is connected to VCC, the "x 16" organization is selected. When it is connected to ground, the "x 8" organization is selected. If the ORG pin is left unconnected and the application does not load the input beyond the capability of the internal 1 Meg ohm pullup, then the "x 16" organization is selected.

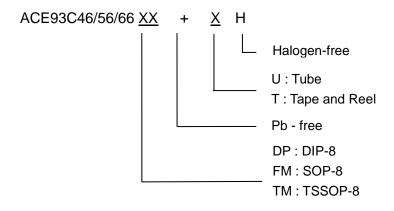
Absolute Maximum Ratings

DC Supply Voltage	-0.3 to 6.5V
Input / Output Voltage	GND -0.3 to Vcc 0.3V
Operating Ambient Temperature	-40 to 85 ℃
Storage Temperature	-65 to 150 ℃

^{*}Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to this device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied or intended. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.



Ordering information



Pin Capacitance

Applicable over recommended operating range from $T_A=25^{\circ}C$, f=1.0MHz,VCC=+1.8V (unless otherwise noted)

Test Conditions	Symbol	Max	Unit	Conditions
Output Capacitance (DO)	COUT	5	pF	VOUT=0V
Input Capacitance (CS, SK, DI)	CIN	5	pF	VIN=0V

DC Characteristics

Applicable over recommended operating range from: $T_A = -40^{\circ}$ C to $+85^{\circ}$ C, $V_{CC} = +1.8$ V to +5.5V, (unless otherwise noted).

Symbol	Parameter	Test Condition	Min	Тур	Max	Units
V _{CC1}	Supply Voltage		1.8		5.5	V
V _{CC2}	Supply Voltage		2.7		5.5	V
V_{CC3}	Supply Voltage		4.5		5.5	V
		$V_{CC} = 5.0V,$				
I _{CC1}	Supply Current	Read at 1.0MHz		0.2	2.0	mA
		Write at 1.0MHz		0.9	3.0	
I _{SB1}	Standby Current	V _{CC} = 1.8V, CS=0V			1.0	μA
I _{SB2}	Standby Current	V _{CC} = 2.7V, CS=0V			1.0	μA
I _{SB3}	Standby Current	V _{CC} = 5.0V, CS=0V			1.0	μA
$I_{LI(1)}$	Input Leakage	$V_{IN} = 0$ to V_{CC}		0.1	1.0	μA
I _{LI(2)}	Input Leakage	$V_{IN} = 0$ to V_{CC}		2.0	3.0	μA
I _{OL}	Output Leakage	$V_{IN} = 0$ to V_{CC}		0.1	1.0	μA
V _{IL1(3)}	Input Low Voltage	$2.7V \leq Vcc \leq 5.5V$	-0.3		0.8	V
V _{IH1(3)}	Input High Voltage	$2.7V \leq Vcc \leq 5.5V$	2.0		Vcc+0.3	V
V _{IL2(3)}	Input Low Voltage	$1.8V \leq Vcc \leq 2.7V$	-0.3		Vcc+0.3	V
V _{IH2(3)}	Input High Voltage	$1.8V \leq Vcc \leq 2.7V$	Vcc*0.7		Vcc+0.3	V



Symbol	Parameter	Test Condition	Тур	Max	Units				
V _{OL1}	Output Low Voltage	$2.7V \leq Vcc \leq 5.5V$							
N/		IOL=2.1mA			0.4	V			
V _{OH1}	Output High Voltage	IOH=-0.4mA	2.4						
V _{OL2}	Output Low Voltage	$1.8V \leq Vcc \leq 2.7V$							
N/		IOL=0.15mA			0.2	V			
V _{OH2}	Output High Voltage	IOH=-100uA	Vcc-0.2						

Note: 1. DI.CS. SK input pin

2. ORG input pin

3. VIL min and VIH max are reference only and are not tested.

Applicable over recommended operating range from: $T_A = -40$ °C to +85 °C, $V_{CC} = +1.8$ V to +5.5V, CL=1TTL Gate and 100pF (unless otherwise noted).

Symbol	Parameter	Test	Condition	Min	Тур	Max	Units
		4.5≦	$4.5 \leq Vcc \leq 5.5v$			2	
fsx	fsx SK Clock Frequency		$Vcc \leq 5.5V$	0		1	MHz
		1.8V≦	≦Vcc≦5.5V	0		0.25	
		4.5≦	Vcc≦5.5v	250			
tskh	SK High Time	2.7≦	Vcc≦5.5V	250			ns
		1.8V≦	≦Vcc≦5.5V	1000			
		4.5≦	Vcc≦5.5v	250			
tskl	SK Low Time	2.7≦	Vcc≦5.5V	250			ns
			≦Vcc≦5.5V	1000			
		4.5≦Vcc≦5.5v		250			
tcs	Minimum CS Low Time	2.7≦	$2.7 \leq Vcc \leq 5.5V$				ns
		1.8V≦	≦Vcc≦5.5V	1000			
		Relative to	$4.5 \leq Vcc \leq 5.5v$	50			
tcss	CS Setup Time	SK	$2.7 \leq Vcc \leq 5.5V$	50			ns
		35	$1.8V \leq Vcc \leq 5.5V$	200			
		Relative to	$4.5 \leq Vcc \leq 5.5v$	100			
tdis	DI Setup Time	SK	$2.7 \leq Vcc \leq 5.5V$	100			ns
		35	$1.8V \leq Vcc \leq 5.5V$	400			
tcsh	CS Hold Time	Relative to SK		0			ns
		Deletive to	4.5≦Vcc≦5.5v	100			
tdih	DI Hold Time	Relative to	$2.7 \leq Vcc \leq 5.5V$	100			ns
		SK	$1.8V \leq Vcc \leq 5.5V$	400			



	Three-wire Serial EEF COM						
Symbol	Parameter	Test	Condition	Min	Тур	Max	Units
			$4.5 \leq Vcc \leq 5.5v$			250	
tpd1	Output Delay to "1"	AC Test	$2.7 \leq Vcc \leq 5.5V$			250	ns
			$1.8V \leq Vcc \leq 5.5V$			1000	
			4.5≦Vcc≦5.5v			250	
tpd0	Output Delay to "0"	AC Test	$2.7 \leq Vcc \leq 5.5V$			250	ns
			$1.8V \leq Vcc \leq 5.5V$			1000	
			4.5≦Vcc≦5.5v			250	
tsv	CS to Status Valid	AC Test	$2.7 \leq Vcc \leq 5.5V$			250	ns
			$1.8V \leq Vcc \leq 5.5V$			1000	
	CC to DO in Llink		4.5≦Vcc≦5.5v			100	
tdf	CS to DO in High	AC Test	$2.7 \leq Vcc \leq 5.5V$			100	ns
	Impedance	CS=VIL	$1.8V \leq Vcc \leq 5.5V$			400	
twp	Write Cycle Time				1.5	5	ms
Endurance ⁽¹⁾	5.0V, 25℃			1M			Write
Endurance	5.0 V, 2 U			I IVI			Cycle

Note: 1. This parameter is characterized and is not 100% tested.

Functional Description

The ACE93C46/56/66 is accessed via a simple and versatile three-wire serial communication interface. Device operation is controlled by seven instructions issued by the host processor. A valid instruction starts with a rising edge of CS and consists of a start bit (logic"1") followed by the appropriate op code and the desired memory address location.

Instruction	SB	OP	Addr	ess	Da	ata	Comments
instruction	30	Code	*8	*16	*8	*16	Comments
READ	1	10	$A_6 - A_0$	A ₅ -A ₀			Read data stored in memory, at specified address
EWEN	1	00	11XXXXX	11XXXX			Write enable must precede all programming modes
REASE	1	11	A_6-A_0	$A_5 - A_0$			Erase memory location An-A0
WRITE	1	01	A_6-A_0	$A_5 - A_0$	$D_7 - D_0$	$D_{15}-D_{0}$	Writes memory location An-A0
ERAL	1	00	10XXXXX	10XXXX			Erases all memory locations. Valid only at VCC=4.5V to 5.5V
WRAL	1	00	01XXXXX	01XXXX	D ₇ -D ₀	D ₁₅ -D ₀	Writes all memory locations. Valid only at VCC=4.5V to 5.5V
EWDS	1	00	00XXXXX	00XXXX			Disables all programming instructions

Instruction Set for the ACE93C46

Notes: The X's in the address field represent don't care values and must be clocked.



Address OP Data Instruction SB Comments Code *8 *16 *8 *16 Read data stored in memory, READ 1 10 $A_8 - A_0$ $A_7 - A_0$ at specified address Write enable must precede all **EWEN** 1 00 11XXXXXX 11XXXXXX programming modes Erase memory location REASE 1 11 $A_8 - A_0$ $A_7 - A_0$ An-A0 Writes memory location WRITE 1 01 $A_8 - A_0$ $D_7 - D_0$ $D_{15}-D_0$ $A_7 - A_0$ An-A0 Erases all memory locations. **ERAL** 1 00 10XXXXXXX 10XXXXXX Valid only at VCC=4.5V to 5.5V Writes all memory locations. WRAL 1 00 01XXXXXXX 01XXXXXX Valid only at VCC=4.5V to $D_7 - D_0$ $D_{15}-D_0$ 5.5V **Disables all programming EWDS** 1 00 00XXXXXXX 00XXXXXX instructions

Instruction Set for the ACE93C56/66

Notes: The X's in the address field represent don't care values and must be clocked.

READ (READ):

The Read (READ) instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that a dummy bit (logic "0") precedes the 8- or 16-bit data output string. The ACE93C56/66 supports sequential read operations. The device will automatically increment the internal address pointer and clock out the next memory location as long as Chip Select (CS) is held high .In this case ,the dummy bit (logic "0")will not be clocked out between memory locations, thus allowing for a continuous steam of data to be read.

ERASE/WRITE (EWEN):

To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable(EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the EWEN state, programming remains enabled until an EWDS instruction is executed or VCC power is removed from the part.

ERASE (ERASE):

The Erase (ERASE) instruction programs all bits in the specified memory location to the logical "1" state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (TCS). A logic "1" at pin DO indicates that the selected memory location has been erased, and the part is ready for another instruction.



WRITE (WRITE):

The Write (WRITE) instruction contains the 8 or 16 bits of data to be written into the specified memory location. The self-timed programming cycle, tWP, starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (TCS). A logic "0" at DO indicates that programming is still in progress. A logic "1" indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. A Ready/Busy status cannot be obtained if the CS is brought high after the end of the selftimed programming cycle, TWP.

ERASE ALL (ERAL):

The Erase All (ERAL) instruction programs every bit in the memory array to the logic "1" state and is primarily used for testing purposes. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (TCS). The ERAL instruction is valid only at VCC = $5.0V \pm 10\%$.

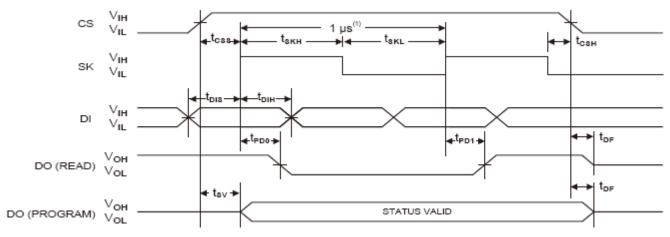
WRITE ALL (WRAL):

The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250ns (TCS). The WRAL instruction is valid only at VCC = $5.0V \pm 10\%$.

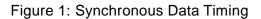
ERASE/WRITE DISABLE (EWDS):

To protect against accidental data disturb, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the Read instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

Timing Diagrams



Note: This is the minimum SK period.





Organization Key for Timing Diagrams

ACE93C46 (1K)		ACE930	C56 (2K)	ACE93C66 (4K)		
1/0	*16	*8	*8	*16	*8	*16
AN	A5	A6	A8 ⁽¹⁾	A7 ⁽²⁾	A8	A7
DN	D15	D7	D7	D15	D7	D15

Note : 1. A8 is a DON'T CARE value ,but the extra clock is required.

2. A7 is a DON'T CARE value ,but the extra clock is required.

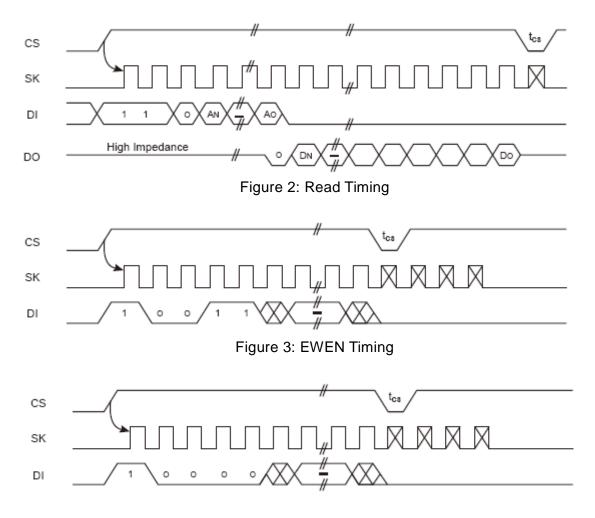
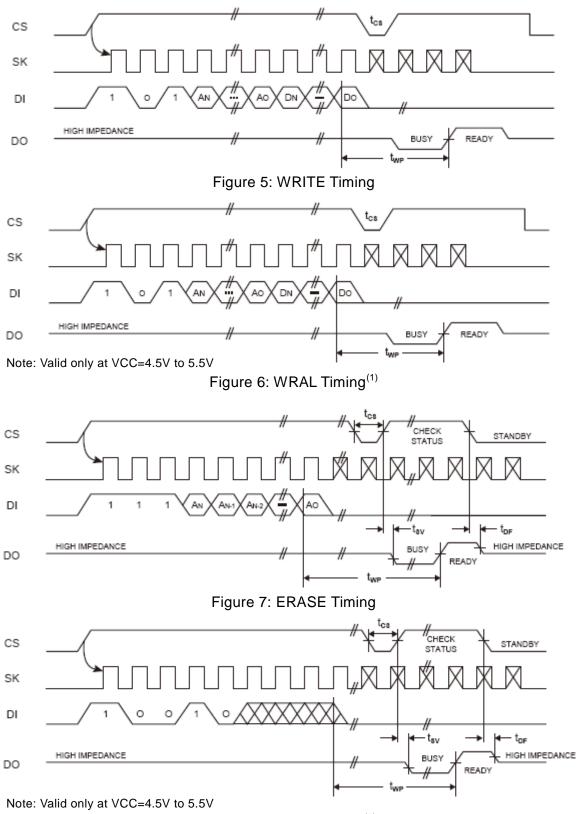


Figure 4: EWDS Timing



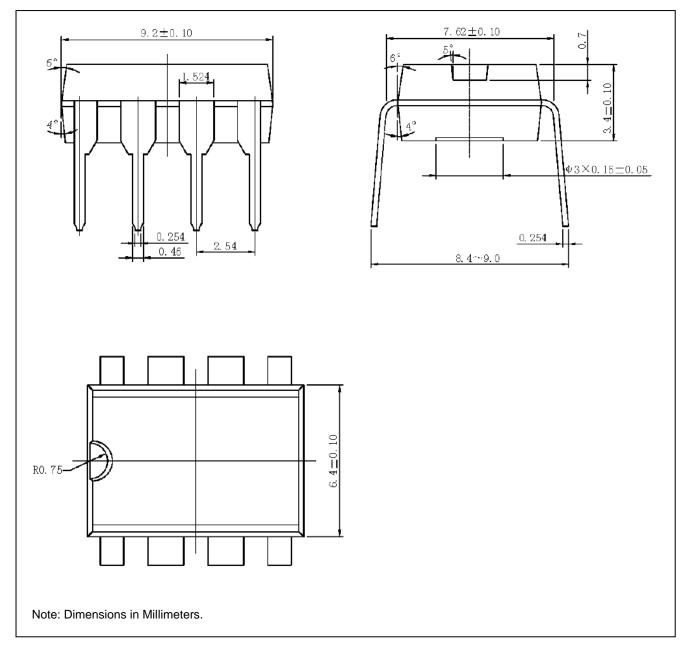






Packaging information

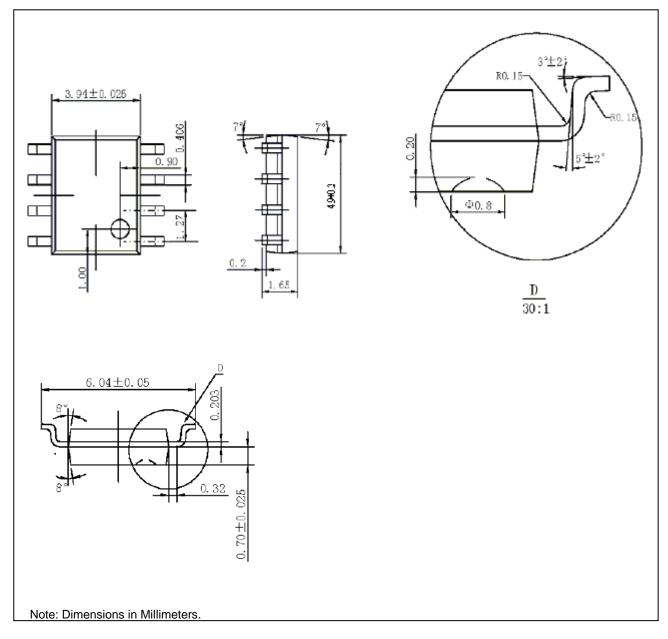
DIP-8





Packaging information

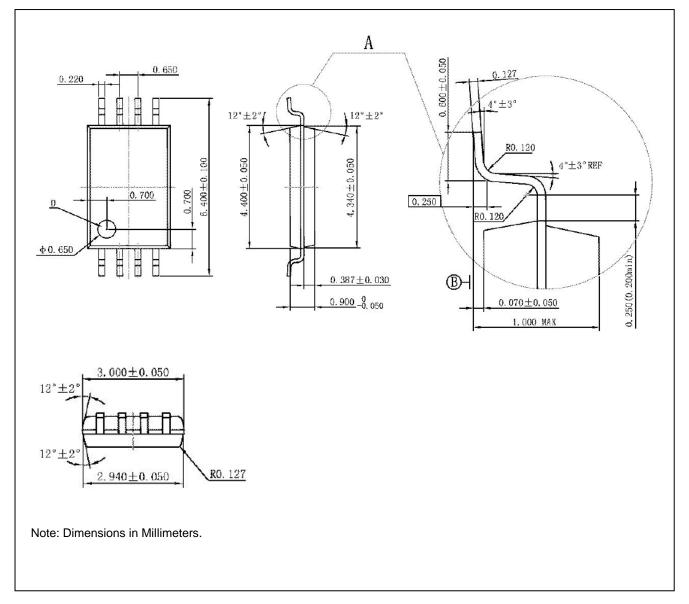
SOP-8





Packaging information

TSSOP-8





Notes

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- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and shoes failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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